1 Features

- Battery Operation
- Minimum External Parts
- Wide Supply Voltage Range: 4 V–12 V or 5 V–18 V
- Low Quiescent Current Drain: 4 mA
- Voltage Gains from 20 to 200
- Ground-Referenced Input
- Self-Centering Output Quiescent Voltage
- Low Distortion: 0.2% \((A_v = 20, V_s = 6 \text{ V}, R_L = 8 \Omega, P_O = 125 \text{ mW}, f = 1 \text{ kHz})\)
- Available in 8-Pin MSOP Package

2 Applications

- AM-FM Radio Amplifiers
- Portable Tape Player Amplifiers
- Intercoms
- TV Sound Systems
- Line Drivers
- Ultrasonic Drivers
- Small Servo Drivers
- Power Converters

3 Description

The LM386M-1 and LM386MX-1 are power amplifiers designed for use in low voltage consumer applications. The gain is internally set to 20 to keep external part count low, but the addition of an external resistor and capacitor between pins 1 and 8 will increase the gain to any value from 20 to 200.

The inputs are ground referenced while the output automatically biases to one-half the supply voltage. The quiescent power drain is only 24 mW when operating from a 6-V supply, making the LM386M-1 and LM386MX-1 ideal for battery operation.

Device Information\(^{(1)}\)

<table>
<thead>
<tr>
<th>PART NUMBER</th>
<th>PACKAGE</th>
<th>BODY SIZE (NOM)</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM386N-1</td>
<td>PDIP (8)</td>
<td>9.60 mm × 6.35 mm</td>
</tr>
<tr>
<td>LM386N-3</td>
<td>PDIP (8)</td>
<td>9.60 mm × 6.35 mm</td>
</tr>
<tr>
<td>LM386N-4</td>
<td>PDIP (8)</td>
<td>9.60 mm × 6.35 mm</td>
</tr>
<tr>
<td>LM386M-1</td>
<td>SOIC (8)</td>
<td>4.90 mm × 3.90 mm</td>
</tr>
<tr>
<td>LM386MX-1</td>
<td>SOIC (8)</td>
<td>4.90 mm × 3.90 mm</td>
</tr>
<tr>
<td>LM386MMX-1</td>
<td>VSSOP (8)</td>
<td>3.00 mm × 3.00 mm</td>
</tr>
</tbody>
</table>

\(^{(1)}\) For all available packages, see the orderable addendum at the end of the data sheet.

---

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.
Table of Contents

1 Features ................................................................. 1
2 Applications ............................................................ 1
3 Description .............................................................. 1
4 Revision History ....................................................... 2
5 Pin Configuration and Functions ................................. 3
6 Specifications ........................................................... 3
   6.1 Absolute Maximum Ratings ................................. 3
   6.2 ESD Ratings ......................................................... 3
   6.3 Recommended Operating Conditions ...................... 4
   6.4 Thermal Information ............................................. 4
   6.5 Electrical Characteristics ...................................... 4
   6.6 Typical Characteristics ......................................... 5
7 Parameter Measurement Information .......................... 6
8 Detailed Description .................................................. 7
   8.1 Overview ............................................................ 7
   8.2 Functional Block Diagram ...................................... 7
   8.3 Feature Description .............................................. 7
   8.4 Device Functional Modes ....................................... 7
9 Application and Implementation ................................. 8
   9.1 Application Information ........................................ 8
   9.2 Typical Application ............................................. 8
10 Power Supply Recommendations ............................... 15
11 Layout ..................................................................... 16
   11.1 Layout Guidelines .............................................. 16
   11.2 Layout Examples ................................................ 16
12 Device and Documentation Support ............................ 18
   12.1 Device Support ................................................... 18
   12.2 Documentation Support ....................................... 18
   12.3 Related Links ..................................................... 18
   12.4 Receiving Notification of Documentation Updates .... 18
   12.5 Community Resources ........................................ 18
   12.6 Trademarks ......................................................... 18
   12.7 Electrostatic Discharge Caution ............................. 18
   12.8 Glossary ........................................................... 18
13 Mechanical, Packaging, and Orderable Information ....... 19

4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (March 2017) to Revision C  Page

• Changed devices LM386M-1/LM386MX-1 To: LM386 in the data sheet title ......................................................... 1
• Changed From: LM386N-4 To: Speaker Impedance in the Recommended Operating Conditions table  ......................... 4
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 1 ............................................................. 8
• Changed kW To: kΩ in the Gain Control section ................. 8
• Changed kW To: kΩ in the Input Biasing section ................. 9
• Changed Figure 11 .................................................... 9
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 2 ............................................................. 10
• Changed Figure 13 .................................................... 10
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 3 ............................................................. 11
• Changed Figure 15 .................................................... 11
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 4 ............................................................. 12
• Changed Figure 17 .................................................... 12
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 5 ............................................................. 13
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 6 ............................................................. 14
• Changed Figure 21 .................................................... 14
• Changed From: 5 Ω to 12 Ω To: 5 V to 12 V for Supply Voltage in Table 7 ............................................................. 15
• Changed Figure 23 .................................................... 15

Changes from Revision A (May 2004) to Revision B  Page

• Added LM386MX-1 device to the data sheet ......................... 1
• Added Device Information, Application and Implementation, Power Supply Recommendation, Layout, and Device and Documentation Support sections ........................................... 1
• Inserted Functional Block Diagram .................................. 7
5 Pin Configuration and Functions

Pin Functions

<table>
<thead>
<tr>
<th>PIN</th>
<th>TYPE</th>
<th>DESCRIPTION</th>
</tr>
</thead>
<tbody>
<tr>
<td>NAME</td>
<td>NO.</td>
<td>-INPUT</td>
</tr>
<tr>
<td>+INPUT</td>
<td>3</td>
<td>Noninverting input</td>
</tr>
<tr>
<td>GND</td>
<td>4</td>
<td>Ground reference</td>
</tr>
<tr>
<td>VOUT</td>
<td>5</td>
<td>Output</td>
</tr>
<tr>
<td>VS</td>
<td>6</td>
<td>Power supply voltage</td>
</tr>
<tr>
<td>BYPASS</td>
<td>7</td>
<td>Bypass decoupling path</td>
</tr>
<tr>
<td>GAIN</td>
<td>8</td>
<td>Gain setting pin</td>
</tr>
</tbody>
</table>

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)\(^{(1)}\)

<table>
<thead>
<tr>
<th>Pin Parameter</th>
<th>MIN</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>Supply Voltage, V(_\text{CC})</td>
<td>LM386N-1/-3, LM386M-1</td>
<td>15</td>
<td>V</td>
</tr>
<tr>
<td></td>
<td>LM386N-4</td>
<td>22</td>
<td></td>
</tr>
<tr>
<td></td>
<td>LM386MM-1</td>
<td>0.595</td>
<td></td>
</tr>
<tr>
<td>Package Dissipation</td>
<td>LM386N</td>
<td>1.25</td>
<td>W</td>
</tr>
<tr>
<td></td>
<td>LM386M</td>
<td>0.73</td>
<td></td>
</tr>
<tr>
<td>Storage temperature, T(_\text{stg})</td>
<td>–65</td>
<td>150</td>
<td>°C</td>
</tr>
</tbody>
</table>

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

<table>
<thead>
<tr>
<th>ESD Parameter</th>
<th>VALUE</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>V(_\text{ESD})</td>
<td>(\pm 1000)</td>
<td>V</td>
</tr>
</tbody>
</table>

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.
6.3 Recommended Operating Conditions

<table>
<thead>
<tr>
<th>Parameter</th>
<th>MIN</th>
<th>NOM</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{CC}$</td>
<td>4</td>
<td>12</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>Speaker Impedance</td>
<td>4</td>
<td>18</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$V_{IN}$</td>
<td>$-0.4$</td>
<td>0.4</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$T_{A}$</td>
<td>0</td>
<td>70</td>
<td>°C</td>
<td></td>
</tr>
</tbody>
</table>

6.4 Thermal Information

<table>
<thead>
<tr>
<th>THERMAL METRIC(1)</th>
<th>LM386D (SOIC)</th>
<th>LM386DGK (VSSOP)</th>
<th>LM386P (PDIP)</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$R_{JA}$ Junction-to-ambient thermal resistance</td>
<td>115.7</td>
<td>169.3</td>
<td>53.4</td>
<td>°C/W</td>
</tr>
<tr>
<td>$R_{JC(top)}$ Junction-to-case (top) thermal resistance</td>
<td>59.7</td>
<td>73.1</td>
<td>42.1</td>
<td>°C/W</td>
</tr>
<tr>
<td>$R_{JB}$ Junction-to-board thermal resistance</td>
<td>56.2</td>
<td>100.2</td>
<td>30.6</td>
<td>°C/W</td>
</tr>
<tr>
<td>$\psi_{JT}$ Junction-top characterization parameter</td>
<td>12.4</td>
<td>9.2</td>
<td>19.0</td>
<td>°C/W</td>
</tr>
<tr>
<td>$\psi_{JB}$ Junction-to-board characterization parameter</td>
<td>55.6</td>
<td>99.1</td>
<td>50.5</td>
<td>°C/W</td>
</tr>
</tbody>
</table>

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

6.5 Electrical Characteristics

<table>
<thead>
<tr>
<th>PARAMETER</th>
<th>TEST CONDITIONS</th>
<th>MIN</th>
<th>TYP</th>
<th>MAX</th>
<th>UNIT</th>
</tr>
</thead>
<tbody>
<tr>
<td>$V_{S}$ Operating Supply Voltage</td>
<td>LM386N-1, -3, LM386N-1M-1, LM386MM-1</td>
<td>4</td>
<td>12</td>
<td>V</td>
<td></td>
</tr>
<tr>
<td>$I_{Q}$ Quiescent Current</td>
<td>$V_{S}$ = 6 V, $V_{IN}$ = 0</td>
<td>4</td>
<td>8</td>
<td>mA</td>
<td></td>
</tr>
<tr>
<td>$P_{OUT}$ Output Power</td>
<td>$V_{S}$ = 6 V, $R_{L}$ = 8 Ω, THD = 10%</td>
<td>250</td>
<td>325</td>
<td>mW</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$V_{S}$ = 9 V, $R_{L}$ = 8 Ω, THD = 10%</td>
<td>500</td>
<td>700</td>
<td>mW</td>
<td></td>
</tr>
<tr>
<td></td>
<td>$V_{S}$ = 16 V, $R_{L}$ = 32 Ω, THD = 10%</td>
<td>700</td>
<td>100</td>
<td>mW</td>
<td></td>
</tr>
<tr>
<td>$A_{V}$ Voltage Gain</td>
<td>$V_{S}$ = 6 V, $f$ = 1 kHz</td>
<td>26</td>
<td>dB</td>
<td></td>
<td></td>
</tr>
<tr>
<td></td>
<td>10 µF from Pin 1 to 8</td>
<td>46</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$BW$ Bandwidth</td>
<td>$V_{S}$ = 6 V, Pins 1 and 8 Open</td>
<td>300</td>
<td>kHz</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$THD$ Total Harmonic Distortion</td>
<td>$V_{S}$ = 6 V, $R_{L}$ = 8 Ω, $P_{OUT}$ = 125 mW</td>
<td>0.2%</td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>$PSRR$ Power Supply Rejection Ratio</td>
<td>$V_{S}$ = 6 V, $f$ = 1 kHz, CBYPASS = 10 µF</td>
<td>50</td>
<td>dB</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$R_{IN}$ Input Resistance</td>
<td>Pins 1 and 8 Open, Referred to Output</td>
<td>50</td>
<td>kΩ</td>
<td></td>
<td></td>
</tr>
<tr>
<td>$I_{BIAS}$ Input Bias Current</td>
<td>$V_{S}$ = 6 V, Pins 2 and 3 Open</td>
<td>250</td>
<td>nA</td>
<td></td>
<td></td>
</tr>
</tbody>
</table>
6.6 Typical Characteristics

Figure 1. Supply Current vs Supply Voltage

Figure 2. Power Supply Rejection vs Frequency

Figure 3. Output Voltage vs Supply Voltage

Figure 4. Voltage Gain vs Frequency

Figure 5. Total Harmonic Distortion vs Frequency

Figure 6. Total Harmonic Distortion vs Power Out
7 Parameter Measurement Information

All parameters are measured according to the conditions described in the Specifications section.
8 Detailed Description

8.1 Overview
The LM386 is a mono low voltage amplifier that can be used in a variety of applications. It can drive loads from 4 Ω to 32 Ω. The gain is internally set to 20 but it can be modified from 20 to 200 by placing a resistor and capacitor between pins 1 and 8. This device comes in three different 8-pin packages as PDIP, SOIC and VSSOP to fit in different applications.

8.2 Functional Block Diagram

8.3 Feature Description
There is an internal 1.35-KΩ resistor that sets the gain of this device to 20. The gain can be modified from 20 to 200. Detailed information about gain setting can be found in the Detailed Design Procedure section.

8.4 Device Functional Modes
As this is an Op Amp it can be used in different configurations to fit in several applications. The internal gain setting resistor allows the LM386 to be used in a very low part count system. In addition a series resistor can be placed between pins 1 and 5 to modify the gain and frequency response for specific applications.
9 Application and Implementation

NOTE
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI’s customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information
Below are shown different setups that show how the LM386 can be implemented in a variety of applications.

9.2 Typical Application

9.2.1 LM386 with Gain = 20

Figure 10 shows the minimum part count application that can be implemented using LM386. Its gain is internally set to 20.

9.2.1.1 Design Requirements

Table 1. Design Parameters

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

9.2.1.2 Detailed Design Procedure

9.2.1.2.1 Gain Control

To make the LM386 a more versatile amplifier, two pins (1 and 8) are provided for gain control. With pins 1 and 8 open the 1.35-kΩ resistor sets the gain at 20 (26 dB). If a capacitor is put from pin 1 to 8, bypassing the 1.35-kΩ resistor, the gain will go up to 200 (46 dB). If a resistor is placed in series with the capacitor, the gain can be set to any value from 20 to 200. Gain control can also be done by capacitively coupling a resistor (or FET) from pin 1 to ground.

Additional external components can be placed in parallel with the internal feedback resistors to tailor the gain and frequency response for individual applications. For example, we can compensate poor speaker bass response by frequency shaping the feedback path. This is done with a series RC from pin 1 to 5 (parallelizing the internal 15-kΩ resistor). For 6 dB effective bass boost: \( R \approx 15 \, kΩ \), the lowest value for good stable operation is \( R = 10 \, kΩ \) if pin 8 is open. If pins 1 and 8 are bypassed then \( R \) as low as 2 kΩ can be used. This restriction is because the amplifier is only compensated for closed-loop gains greater than 9.
9.2.1.2.2 Input Biasing

The schematic shows that both inputs are biased to ground with a 50 kΩ resistor. The base current of the input transistors is about 250 nA, so the inputs are at about 12.5 mV when left open. If the dc source resistance driving the LM386 is higher than 250 kΩ it will contribute very little additional offset (about 2.5 mV at the input, 50 mV at the output). If the dc source resistance is less than 10 kΩ, then shorting the unused input to ground will keep the offset low (about 2.5 mV at the input, 50 mV at the output). For dc source resistances between these values we can eliminate excess offset by putting a resistor from the unused input to ground, equal in value to the dc source resistance. Of course all offset problems are eliminated if the input is capacitively coupled.

When using the LM386 with higher gains (bypassing the 1.35 kΩ resistor between pins 1 and 8) it is necessary to bypass the unused input, preventing degradation of gain and possible instabilities. This is done with a 0.1 μF capacitor or a short to ground depending on the dc source resistance on the driven input.

9.2.1.3 Application Curve

Figure 11. Supply Current vs Supply Voltage
9.2.2 LM386 with Gain = 200

![Diagram of LM386 with Gain = 200]

Figure 12. LM386 with Gain = 200

9.2.2.1 Design Requirements

Table 2. Design Parameters

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

9.2.2.2 Detailed Design Procedure

The Detailed Design Procedure can be found in the Detailed Design Procedure section.

9.2.2.3 Application Curve

![Application Curve Graph]

Figure 13. Supply Current vs Supply Voltage
9.2.3 LM386 with Gain = 50

![LM386 schematic diagram](image)

Figure 14. LM386 with Gain = 50

### 9.2.3.1 Design Requirements

#### Table 3. Design Parameters

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

### 9.2.3.2 Detailed Design Procedure

The Detailed Design Procedure can be found in the *Detailed Design Procedure* section.

### 9.2.3.3 Application Curve

![Supply Current vs Supply Voltage graph](image)

Figure 15. Supply Current vs Supply Voltage
9.2.4 Low Distortion Power Wienbridge Oscillator

![Circuit Diagram](image)

**Figure 16. Low Distortion Power Wienbridge Oscillator**

### 9.2.4.1 Design Requirements

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

### 9.2.4.2 Detailed Design Procedure

The Detailed Design Procedure can be found in the [Detailed Design Procedure](#) section.

### 9.2.4.3 Application Curve

![Graph](image)

**Figure 17. Supply Current vs Supply Voltage**
9.2.5 LM386 with Bass Boost

![LM386 with Bass Boost Diagram](image)

Figure 18. LM386 with Bass Boost

9.2.5.1 Design Requirements

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

9.2.5.2 Detailed Design Procedure

The Detailed Design Procedure can be found in the Detailed Design Procedure section.

9.2.5.3 Application Curve

![Voltage Gain vs Frequency Graph](image)

Figure 19. Voltage Gain vs Frequency
9.2.6 Square Wave Oscillator

![Square Wave Oscillator Diagram]

Table 6. Design Parameters

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

9.2.6.1 Detailed Design Procedure

The Detailed Design Procedure can be found in the *Detailed Design Procedure* section.

9.2.6.2 Application Curve

![Supply Current vs Supply Voltage Graph]

Figure 21. Supply Current vs Supply Voltage
9.2.7 AM Radio Power Amplifier

![AM Radio Power Amplifier Diagram]

**Figure 22. AM Radio Power Amplifier**

9.2.7.1 Design Requirements

<table>
<thead>
<tr>
<th>DESIGN PARAMETER</th>
<th>EXAMPLE VALUE</th>
</tr>
</thead>
<tbody>
<tr>
<td>Load Impedance</td>
<td>4 Ω to 32 Ω</td>
</tr>
<tr>
<td>Supply Voltage</td>
<td>5 V to 12 V</td>
</tr>
</tbody>
</table>

9.2.7.2 Detailed Design Procedure

The Detailed Design Procedure can be found in the *Detailed Design Procedure* section.

9.2.7.3 Application Curve

![Supply Current vs Supply Voltage Graph]

**Figure 23. Supply Current vs Supply Voltage**

10 Power Supply Recommendations

The LM386 is specified for operation up to 12 V or 18 V. The power supply should be well regulated and the voltage must be within the specified values. It is recommended to place a capacitor to GND close to the LM386 power supply pin.
11 Layout

11.1 Layout Guidelines
Place all required components as close as possible to the device. Use short traces for the output to the speaker connection. Route the analog traces far from the digital signal traces and avoid crossing them.

11.2 Layout Examples

Figure 24. Layout Example for Minimum Parts Gain = 20 dB on PDIP package

Figure 25. Layout Example for Minimum Parts Gain = 20 dB on SOIC package
Layout Examples (continued)

Figure 26. Layout Example for Minimum Parts Gain = 20 dB on VSSOP package
12 Device and Documentation Support

12.1 Device Support

12.1.1 Development Support

12.2 Documentation Support

12.3 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

<table>
<thead>
<tr>
<th>PARTS</th>
<th>PRODUCT FOLDER</th>
<th>ORDER NOW</th>
<th>TECHNICAL DOCUMENTS</th>
<th>TOOLS &amp; SOFTWARE</th>
<th>SUPPORT &amp; COMMUNITY</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM386M-1</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
</tr>
<tr>
<td>LM386MX-1</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
<td>Click here</td>
</tr>
</tbody>
</table>

12.4 Receiving Notification of Documentation Updates

To receive notification of documentation updates — go to the product folder for your device on ti.com. In the upper right-hand corner, click the Alert me button to register and receive a weekly digest of product information that has changed (if any). For change details, check the revision history of any revised document.

12.5 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI’s views; see TI’s Terms of Use.

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.6 Trademarks

E2E is a trademark of Texas Instruments. All other trademarks are the property of their respective owners.

12.7 Electrostatic Discharge Caution

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.8 Glossary

**SLYZ022** — *TI Glossary.*

This glossary lists and explains terms, acronyms, and definitions.
13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
# PACKAGING INFORMATION

<table>
<thead>
<tr>
<th>Orderable Device</th>
<th>Status</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>Package Qty</th>
<th>Eco Plan / Ball material</th>
<th>MSL Peak Temp</th>
<th>Op Temp (°C)</th>
<th>Device Marking</th>
<th>Samples</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM386M-1/NOPB</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>95</td>
<td>RoHS &amp; Green</td>
<td>SN</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>LM386M-1</td>
</tr>
<tr>
<td>LM386MMX-1/NOPB</td>
<td>ACTIVE</td>
<td>VSSOP</td>
<td>DGK</td>
<td>8</td>
<td>3500</td>
<td>RoHS &amp; Green</td>
<td>SN</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>Z86</td>
</tr>
<tr>
<td>LM386MX-1/NOPB</td>
<td>ACTIVE</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>RoHS &amp; Green</td>
<td>SN</td>
<td>Level-1-260C-UNLIM</td>
<td>0 to 70</td>
<td>LM386M-1</td>
</tr>
<tr>
<td>LM386N-1/NOPB</td>
<td>ACTIVE</td>
<td>PDIP</td>
<td>P</td>
<td>8</td>
<td>40</td>
<td>RoHS &amp; Green</td>
<td>NIPDAU</td>
<td>Level-1-NA-UNLIM</td>
<td>0 to 70</td>
<td>LM386N-1</td>
</tr>
<tr>
<td>LM386N-3/NOPB</td>
<td>ACTIVE</td>
<td>PDIP</td>
<td>P</td>
<td>8</td>
<td>40</td>
<td>RoHS &amp; Green</td>
<td>NIPDAU</td>
<td>Level-1-NA-UNLIM</td>
<td>0 to 70</td>
<td>LM386N-3</td>
</tr>
<tr>
<td>LM386N-4/NOPB</td>
<td>ACTIVE</td>
<td>PDIP</td>
<td>P</td>
<td>8</td>
<td>40</td>
<td>RoHS &amp; Green</td>
<td>NIPDAU</td>
<td>Level-1-NA-UNLIM</td>
<td>0 to 70</td>
<td>LM386N-4</td>
</tr>
</tbody>
</table>

(1) The marketing status values are defined as follows:
- **ACTIVE**: Product device recommended for new designs.
- **LIFEBUY**: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
- **NRND**: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
- **PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.
- ** OBSOLETE**: TI has discontinued the production of the device.

(2) **RoHS**: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
- **RoHS Exempt**: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
- **Green**: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.
### TAPE AND REEL INFORMATION

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Pins</th>
<th>SPQ</th>
<th>Reel Diameter (mm)</th>
<th>Reel Width W1 (mm)</th>
<th>A0   (mm)</th>
<th>B0   (mm)</th>
<th>K0   (mm)</th>
<th>P1   (mm)</th>
<th>W    (mm)</th>
<th>Pin1 Quadrant</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM386MMX-1/NOPB</td>
<td>VSSOP</td>
<td>8</td>
<td>3500</td>
<td>330.0</td>
<td>12.4</td>
<td>5.3</td>
<td>3.4</td>
<td>1.4</td>
<td>8.0</td>
<td>12.0</td>
<td>Q1</td>
</tr>
<tr>
<td>LM386MX-1/NOPB</td>
<td>SOIC</td>
<td>8</td>
<td>2500</td>
<td>330.0</td>
<td>12.4</td>
<td>6.5</td>
<td>5.4</td>
<td>2.0</td>
<td>8.0</td>
<td>12.0</td>
<td>Q1</td>
</tr>
</tbody>
</table>

*All dimensions are nominal.*

- **Device**: The model of the device.
- **Package Type**: The type of package used.
- **Pins**: The number of pins on the device.
- **SPQ**: The spindle pack quantity.
- **Reel Diameter**: The diameter of the reel in millimeters.
- **Reel Width**: The width of the reel in millimeters.
- **A0**: Dimension designed to accommodate the component width.
- **B0**: Dimension designed to accommodate the component length.
- **K0**: Dimension designed to accommodate the component thickness.
- **W**: Overall width of the carrier tape.
- **P1**: Pitch between successive cavity centers.

---

*Images and diagrams not included in this text representation.*
## TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Type</th>
<th>Package Drawing</th>
<th>Pins</th>
<th>SPQ</th>
<th>Length (mm)</th>
<th>Width (mm)</th>
<th>Height (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM386MMX-1/NOPB</td>
<td>VSSOP</td>
<td>DGK</td>
<td>8</td>
<td>3500</td>
<td>367.0</td>
<td>367.0</td>
<td>35.0</td>
</tr>
<tr>
<td>LM386MX-1/NOPB</td>
<td>SOIC</td>
<td>D</td>
<td>8</td>
<td>2500</td>
<td>367.0</td>
<td>367.0</td>
<td>35.0</td>
</tr>
</tbody>
</table>
### TUBE

![Diagram of TUBE dimensions](image)

- **T** - Tube height
- **L** - Tube length
- **W** - Tube width
- **B** - Alignment groove width

*All dimensions are nominal*

<table>
<thead>
<tr>
<th>Device</th>
<th>Package Name</th>
<th>Package Type</th>
<th>Pins</th>
<th>SPQ</th>
<th>L (mm)</th>
<th>W (mm)</th>
<th>T (µm)</th>
<th>B (mm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>LM386M-1/NOPB</td>
<td>D</td>
<td>SOIC</td>
<td>8</td>
<td>95</td>
<td>495</td>
<td>8</td>
<td>4064</td>
<td>3.05</td>
</tr>
<tr>
<td>LM386N-1/NOPB</td>
<td>P</td>
<td>PDIP</td>
<td>8</td>
<td>40</td>
<td>502</td>
<td>14</td>
<td>11938</td>
<td>4.32</td>
</tr>
<tr>
<td>LM386N-3/NOPB</td>
<td>P</td>
<td>PDIP</td>
<td>8</td>
<td>40</td>
<td>502</td>
<td>14</td>
<td>11938</td>
<td>4.32</td>
</tr>
<tr>
<td>LM386N-4/NOPB</td>
<td>P</td>
<td>PDIP</td>
<td>8</td>
<td>40</td>
<td>502</td>
<td>14</td>
<td>11938</td>
<td>4.32</td>
</tr>
</tbody>
</table>
NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.
NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.
P (R-PDIP-T8)  PLASTIC DUAL-IN-LINE PACKAGE

NOTES:  
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS-001 variation BA.

4040082/E  04/2010
DGK (S-PDSO-G8)  PLASTIC SMALL-OUTLINE PACKAGE

NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
   ▶ Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
   ▶ Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
E. Falls within JEDEC MO-187 variation AA, except interlead flash.

4073329/E 05/06
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC-7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.
IMPORTANT NOTICE AND DISCLAIMER
TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES “AS IS” AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI’s products are provided subject to TI’s Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI’s provision of these resources does not expand or otherwise alter TI’s applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2022, Texas Instruments Incorporated